

# 3.3V VCXO and Low Noise PLL Clock Generator for Digital Video Applications

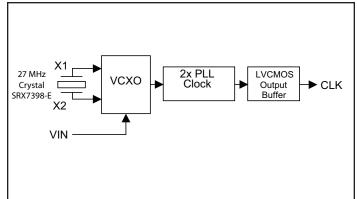
#### **Features**

- Fully integrated 27 MHz VCXO and low phase noise 2x PLL clock genereator
- Uses a SaRonix 27 MHz crystal for optimum performance
- · On-chip (patented) VCXO with wide pull range
- · Low phase noise LVCMOS output
- 12mA output drive capability at TTL levels
- $3.3V \pm 5\%$  operating voltage
- Packaging (Pb-free & Green):
  - 8-pin SOIC (W)

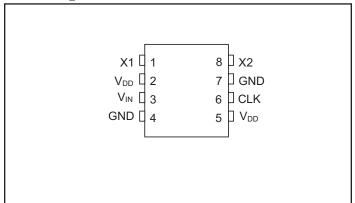
## **Description**

The PI6CX233 is a  $3.3V \pm 5\%$  VCXO and low phase noise 2x PLL clock generator available in discrete IC form with external SaRonix crystal. The PI6CX233 features a low-noise 2x clock multiplication circuit with improved phase noise performance and LVCMOS output clock signal. The device accepts an external analog control voltage signal that pulls the output frequency by  $\pm 120$ ppm. Contact Pericom/SaRonix for recommended crystal specifications.

## **Block Diagram**



## **Pin Configuration**



#### **Pin Functions**

Pin Name	Number	Туре	Description
X1, X2	1, 8	I	External crystal
$V_{\mathrm{DD}}$	2	PWR	3.3V Positive power supply. Bypass with $0.1\mu F \parallel 0.01\mu F$ capacitors and place as close to the V <sub>DD</sub> pins as possible.
GND	4, 7	PWR	Ground
V <sub>IN</sub>	3	I	Analog control VCXO voltage input
CLK	6	О	54 MHz clock output



# **Maximum Ratings**

	Storage Temperature	55°C to +125°C
	Operating Temperature	0°C to +70°C
	Supply Voltage V <sub>DD</sub>	0.5V to +7V
	Inputs/Outputs Voltage	-0.5V to V <sub>DD</sub> +0.5V
	Output Current	50mA
	Soldering Lead Temperature (10s)	+260°C
	Junction Temperature	50°C to +150°C
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#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **DC Electrical Characteristics**

(Unless otherwise specified,  $V_{DD}$  = +3.3V ±5%,  $V_{IN}$  = 0.5 $V_{DD}$ ,  $f_{O}$  = 54 MHz,  $C_{CLK}$  = 5pF,  $T_{A}$  = 0°C to +70°C)

Symbol	Description	Test Condition	Min.	Тур.	Max.	Units
$V_{ m DD}$	Operating Supply Voltage		+3.15	+3.3	+3.45	V
$I_{\mathrm{DD}}$	Operating Supply Current			45	55	mA
V <sub>IH</sub>	Input HIGH Voltage		+2.0			V
$V_{ m IL}$	Input LOW Voltage				+0.8	V
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH} = -12 \text{ mA}$	2.4			V
V <sub>OL</sub>	Output LOW Voltage	$I_{OL} = +12 \text{ mA}$			0.4	V

## **AC Electrical Characteristics**

(Unless otherwise specified,  $V_{DD} = +3.3V \pm 5\%$ ,  $V_{IN} = 0.5V_{DD}$ ,  $f_O = 54$  MHz,  $C_{CLK} = 5$ pF,  $T_A = 0$ °C to +70°C)

Symbol	Description	Test Condition	Min.	Typ.	Max.	Units
$f_i$	Crystal Input Frequency		24	27	30	
$f_{O}$	Output Frequency		48	54	60	MHz
$T_R/T_F$	CLK Rise / Fall Time	Rise Time: 20% to 80% Fall Time: 80% to 20%		0.6	1.0	ns
$T_{DC}$	CLK Duty Cycle	at V <sub>DD</sub> /2	48	50	52	%
$T_{PN1}$	CLK Phase Noise @ 1kHz offset			-104		dBc/Hz
T <sub>PN2</sub>	CLK Phase Noise @ 10 kHz offset			-118		dBc/Hz
T <sub>PN3</sub>	CLK Phase Noise @ 100 kHz offset			-120		dBc/Hz
T <sub>PN4</sub>	CLK Phase Noise @ 1 MHz offset			-116		dBc/Hz
T <sub>PN5</sub>	CLK Phase Noise @ 10 MHz offset			-140		dBc/Hz
$T_{\mathrm{S}}$	Oscillator Start Time	$V_{\rm DD} = 0.9 V_{\rm DD}$			12	ms
$ m J_{ST}$	Period Jitter	$C_L = 15pF$		110		ps



## **VCXO** Electrical Characteristic

(Unless otherwise specified,  $V_{DD} = +3.3V \pm 5\%$ ,  $f_O = 54$  MHz,  $C_{CLK} = 5$ pF,  $T_A = 0$ °C to +70°C)

Symbol	Description	<b>Test Condition</b>	Min.	Тур.	Max.	Units
$V_{\rm IN}$	Control Voltage Input		0		$V_{\mathrm{DD}}$	V
$\Delta F_{ m CLK}$	Control Pull Range	$V_{IN} = 0$ to $V_{DD}$		±120		ppm
$L_{\rm IN}$	Monotonic Linearity				10	%
MB	Modulation Bandwidth	$V_{IN} = 0.5V_{DD}$		20		kHz

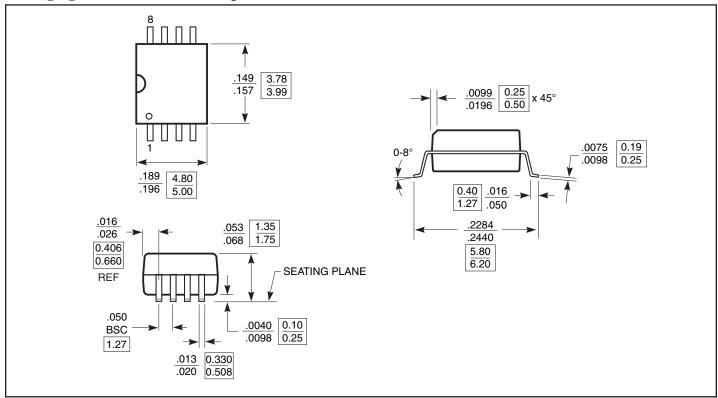
## Recommended Crystal: Pericom/Saronix SRX7398-E Crystal

The PI6CX233 consists of an integrated 27 MHz VCXO and PLL circuit. The VCXO was designed to operate at 27 MHz (center frequency), with  $C_{LXTAL} = 12$ pF.  $C_{LXTAL}$  includes the on-chip + stray + external pull capacitance. The pull capacitors should be placed as close as possible to the PI6CX233 and should be placed on the same side of the board as the PI6CX233. There should be no signal traces underneath or close to the crystal to prevent coupling of unwanted signals.

Description	Crystal
Mode of Oscillation and Cut	Fundamental AT
Frequency (as specified)	27 MHz
Frequency Tolerance	±20ppm
Temperature plus Aging Stability	±30ppm
C0 /C1	230
Load Capacitance (C <sub>LXTAL</sub> )	12pF
Equivalent Series Resistance (ESR)	35Ω (max.)



## Packaging Mechanical: Plastic 8-pin SOIC (W)



# Ordering Information<sup>(1,2,3)</sup>

Ordering Code	Package Code	Crystal Input (MHz)	Clock Output (MHz)	Package Description
PI6CX233WE	W	24 to 30	48 to 60	Pb-free & Green, 8-pin SOIC

#### **Notes:**

- 1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- 2. E = Pb-free and Green
- 3. X Suffix = Tape/Reel